

SuperMOS –SOP8 30V BV_{DSS}, 10.5mΩ R_{DS(on)}, N-channel MOSFET

1. Description

The AO4468-ES is N-Channel enhancement MOS Field Effect Transistor. Uses advanced trench technology and design to provide excellent R_{DS(ON)} with low gate charge. Device is suitable for use in DC-DC conversion, power switch and charging circuit. Standard Product AO4468-ES is Pb-free.

2. Features

- 30V, R_{DS(ON)}=10.5mΩ(TYP.) @V_{GS}=10V
- R_{DS(ON)}=15.5mΩ(TYP.) @V_{GS}=4.5V
- Use trench MOSFET technology
- High density cell design for low R_{DS(on)}
- Material: Halogen free
- Reliable and rugged
- Avalanche Rated
- Low leakage current

3. Applications

- PWM applications
- Load switch
- Power management in portable/desktop PCs
- DC/DC conversion

100% UIS TESTED

4. Ordering Information

| Part Number | Package | Marking | Material | Packing | Quantity per reel | Flammability Rating | Reel Size |
|-------------|---------|-------------|--------------|-------------|-------------------|---------------------|-----------|
| AO4468-ES | SOP8 | ES4406A/lot | Halogen free | Tape & Reel | 3,000 PCS | UL 94V-0 | 13 inches |

Table-1 Ordering information

5. Pin Configuration and Functions


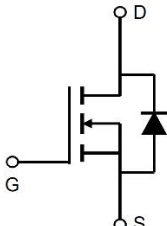
| Pin | Function | Outline | Circuit Diagram |
|---------|----------|---|---|
| 1/2/3 | Source |  |  |
| 4 | Gate | | |
| 5/6/7/8 | Drain | | |

Table-2 Pin configuration

6. Specification

Absolute Maximum Rating & Thermal Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

| Parameter | Symbol | Limit | Unit | |
|-----------------------------------|------------|-------------------|------|---|
| Drain-Source Voltage | BV_{DSS} | 30 | V | |
| Gate-Source Voltage | V_{GS} | ±20 | V | |
| Continuous Drain Current | I_D | $T_A=25^{\circ}C$ | 10 | A |
| | | $T_A=75^{\circ}C$ | 7.8 | |
| Maximum Power Dissipation | P_D | $T_A=25^{\circ}C$ | 3.2 | W |
| | | $T_A=75^{\circ}C$ | 1.9 | |
| Pulsed Drain Current ^a | I_{DM} | 40 | A | |
| Operating Junction Temperature | T_J | 150 | °C | |
| Lead Temperature | T_L | 260 | °C | |
| Storage Temperature Range | T_{stg} | -55 to 150 | °C | |

Thermal resistance ratings

| Single Operation | | | | | |
|---|---------------|-----------------|---------|---------|------|
| Parameter | | Symbol | Typical | Maximum | Unit |
| Junction-to-Ambient Thermal Resistance ^a | $t \leq 10$ s | $R_{\theta JA}$ | 32 | 40 | °C/W |

Note:

a: Surface mounted on FR4 Board using 1 square inch pad size, 1oz copper

Electrical Characteristics

At TA = 25°C unless otherwise specified

| Parameter | Symbol | Test Conditions | Min. | Typ. | Max. | Unit |
|--|--------------|---|------|------|-----------|------------|
| OFF CHARACTERISTICS | | | | | | |
| Drain-to-Source Breakdown Voltage | BV_{DSS} | $V_{GS}=0V, I_D=250\mu A$ | 30 | | | V |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS}=30V, V_{GS}=0V$ | | | 1.0 | μA |
| Gate-to-source Leakage Current | I_{GSS} | $V_{DS}=0V, V_{GS}=\pm 20V$ | | | ± 100 | nA |
| ON CHARACTERISTICS | | | | | | |
| Gate Threshold Voltage | $V_{GS(TH)}$ | $V_{GS}=V_{DS}, I_D=250\mu A$ | 1.0 | 1.5 | 2.4 | V |
| Drain-to-source On-resistance | $R_{DS(on)}$ | $V_{GS}=10V, I_D=10A$ | | 10.5 | 19 | m Ω |
| | | $V_{GS}=4.5V, I_D=8A$ | | 15.5 | 26 | |
| Forward Trans conductance | g_{FS} | $V_{DS}=5.0V, I_D=10A$ | | | 80 | S |
| CHARGES, CAPACITANCES AND GATE RESISTANCE | | | | | | |
| Input Capacitance | C_{ISS} | $V_{GS}=0V, f=1MHz,$ $V_{DS}=15V$ | | 750 | | pF |
| Output Capacitance | C_{OSS} | | | 125 | | |
| Reverse Transfer Capacitance | C_{RSS} | | | 70 | | |
| Total Gate Charge | $Q_{G(TOT)}$ | $V_{GS}=4.5V, V_{DS}=15V,$ $I_D=10A$ | | 15 | | nC |
| Gate-to-Source Charge | Q_{GS} | | | 2.5 | | |
| Gate-to-Drain Charge | Q_{GD} | | | 3 | | |
| SWITCHING CHARACTERISTICS | | | | | | |
| Turn-On Delay Time | $t_{d(ON)}$ | $V_{GS}=10V, V_{DS}=15V,$ $R_L=1.5\Omega, R_{GEN}=3\Omega$ | | 4.5 | | ns |
| Rise Time | t_r | | | 10 | | |
| Turn-Off Delay Time | $t_{d(OFF)}$ | | | 18 | | |
| Fall Time | t_f | | | 6 | | |
| BODY DIODE CHARACTERISTICS | | | | | | |
| Forward Voltage | V_{SD} | $V_{GS}=0V, I_S=1.0A$ | 0.45 | | 1.2 | V |

7. Typical Characteristic

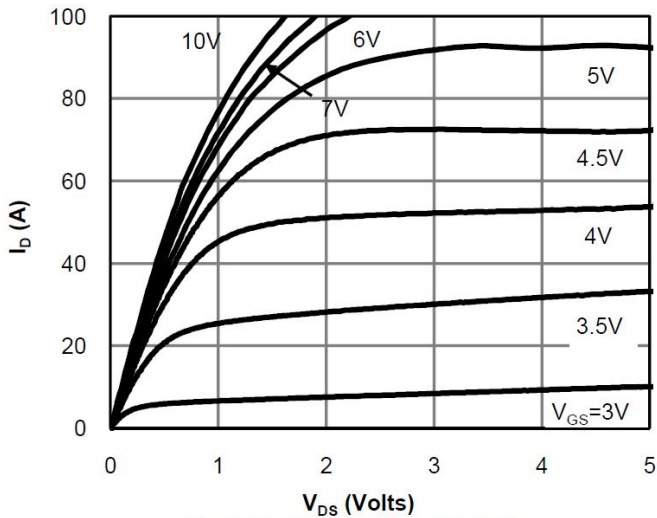


Fig 1: On-Region Characteristics

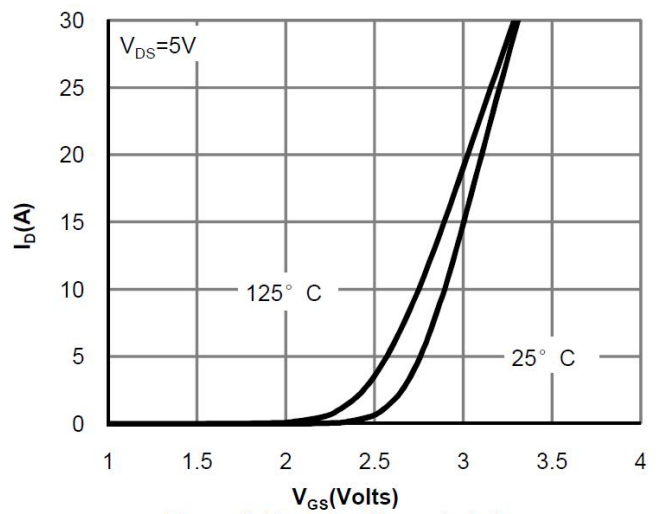


Figure 2: Transfer Characteristics

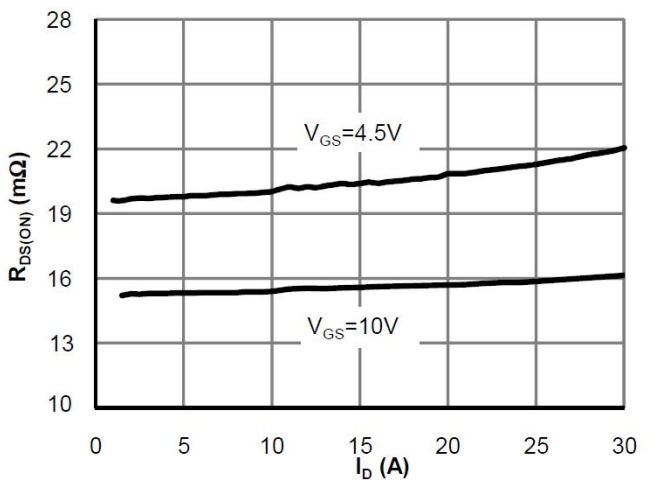


Figure 3: On-Resistance vs. Drain Current and Gate Voltage

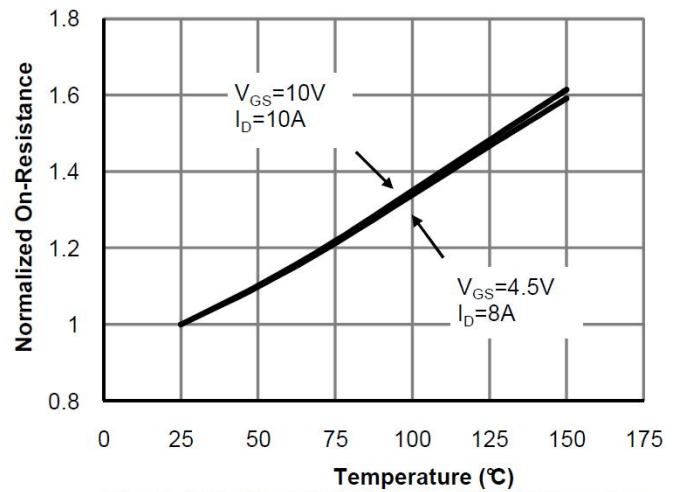


Figure 4: On-Resistance vs. Junction Temperature

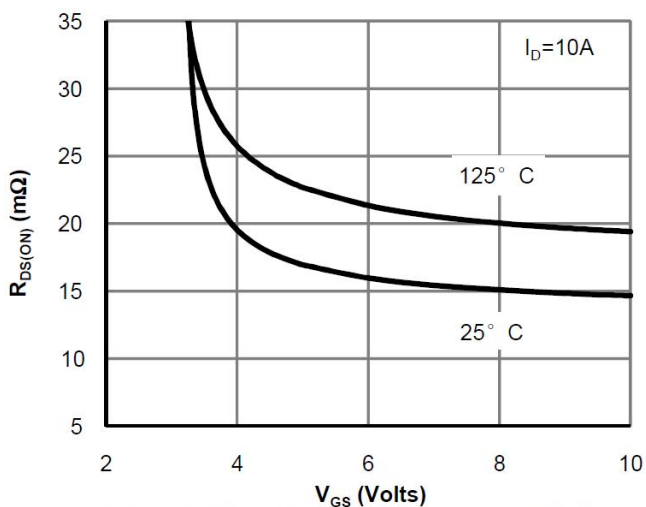


Figure 5: On-Resistance vs. Gate-Source Voltage

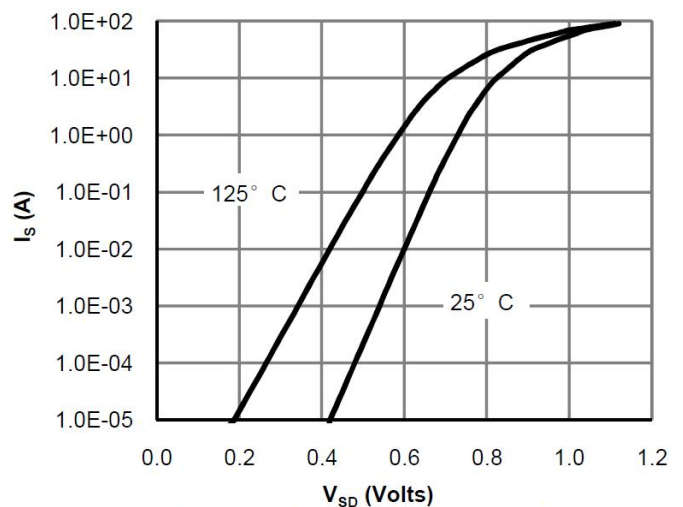


Figure 6: Body-Diode Characteristics

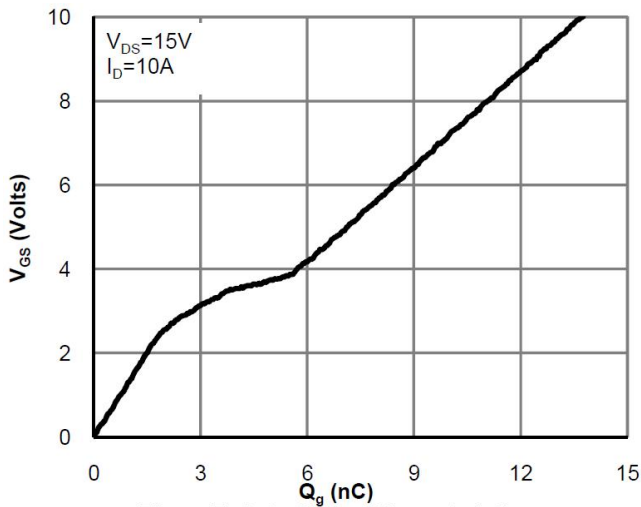


Figure 7: Gate-Charge Characteristics

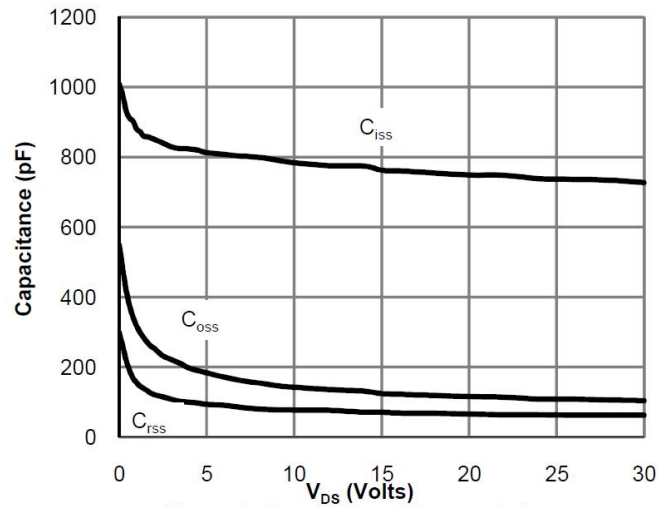


Figure 8: Capacitance Characteristics

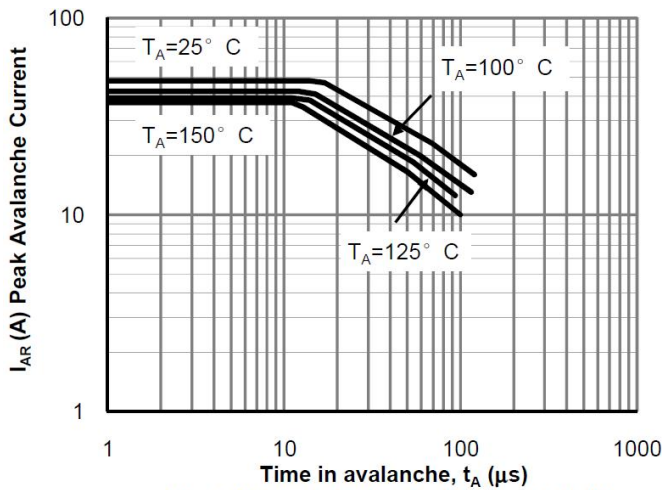


Figure 9: Single Pulse Avalanche capability

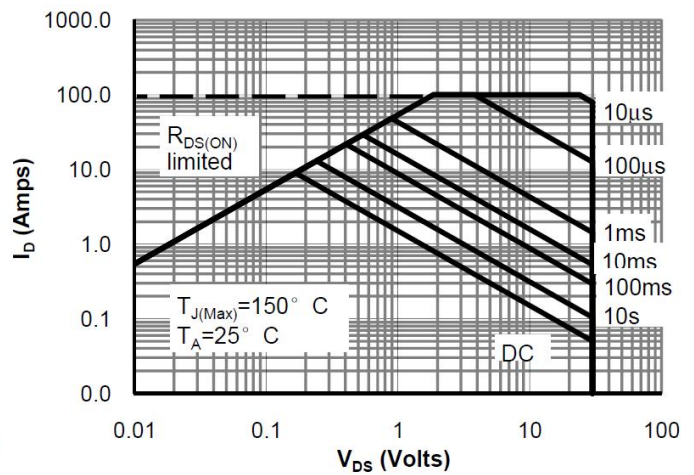


Figure 10: Maximum Forward Biased Safe Operating Area

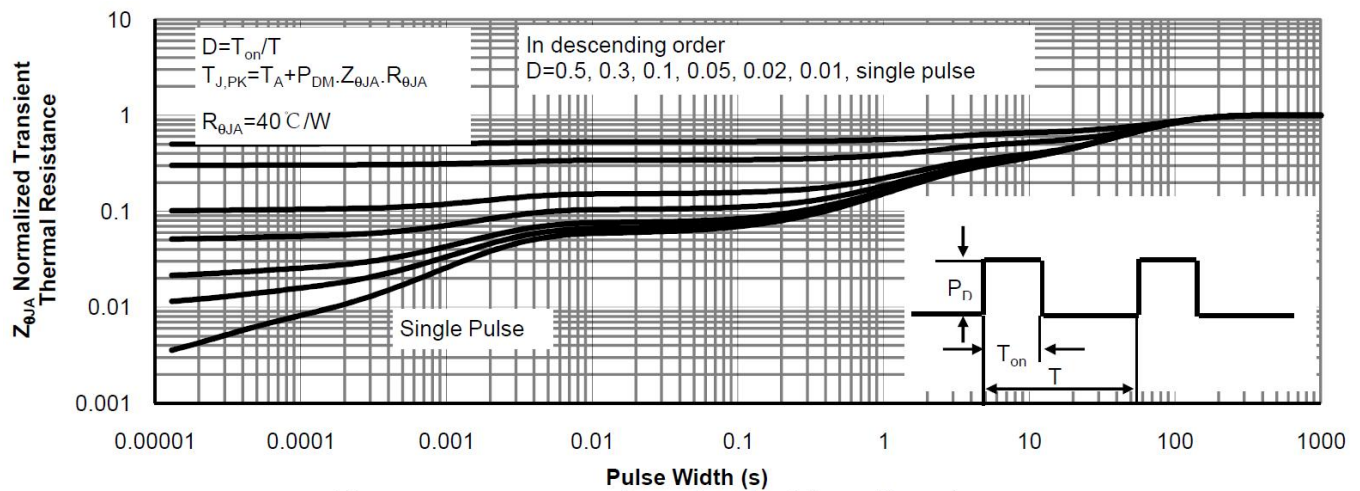
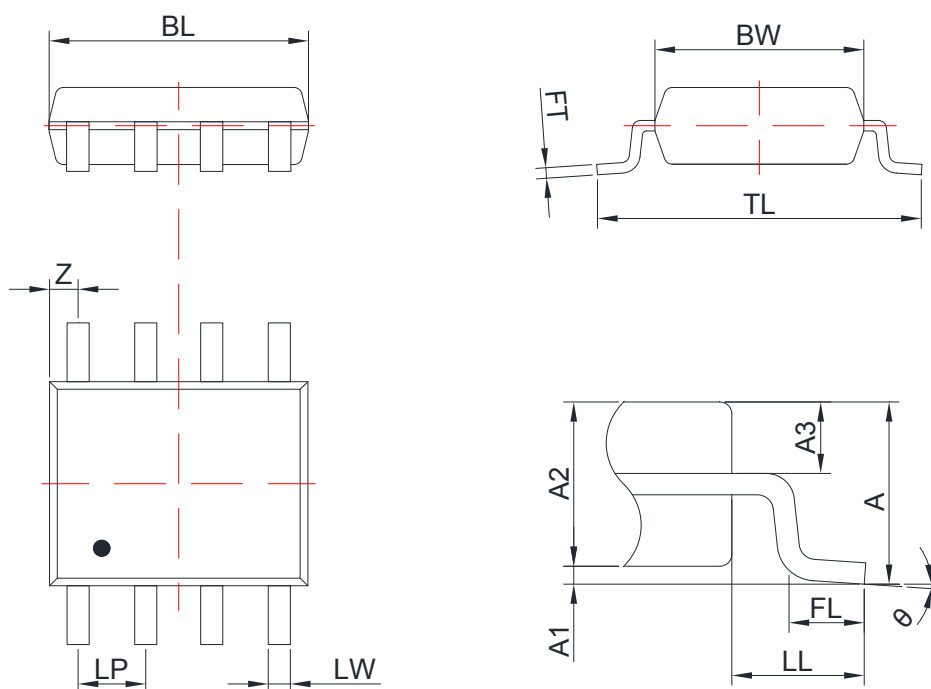


Figure 11: Normalized Maximum Transient Thermal Impedance

8. Dimension (SOP8)



COMMON DIMENSIONS: UNITS OF MEASURE=MILLIMETER

| Symbol | Dimensions | | Symbol | Dimensions | |
|--------|------------|------|--------|------------|------|
| | Min. | Max. | | Min. | Max. |
| A | 1.75 | | FL | 0.50 | 0.80 |
| A1 | 0.05 | 0.15 | LP | 1.25 | 1.30 |
| A2 | 1.40 | 1.50 | LL | 1.1 BSC | |
| A3 | 0.623 BSC | | LW | 0.38 | 0.43 |
| BL | 4.80 | 5.00 | TL | 5.90 | 6.10 |
| BW | 3.70 | 4.10 | Z | 0.54 | |
| FT | 0.20 | 0.21 | theta | 0° | 8° |

DISCLAIMER

ELECSUPER PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with ElecSuper products. You are solely responsible for

- (1) selecting the appropriate ElecSuper products for your application;
- (2) designing, validating and testing your application;
- (3) ensuring your application meets applicable standards, and any other safety, security, or other requirements.

These resources are subject to change without notice. ElecSuper grants you permission to use these resources only for development of an application that uses the ElecSuper products described in the resource. Other reproduction and display of these resources are prohibited. No license is granted to any other ElecSuper intellectual property right or to any third party intellectual property right. ElecSuper disclaims responsibility for, and you will fully indemnify ElecSuper and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources. ElecSuper's products are provided subject to ElecSuper's Terms of Sale or other applicable terms available either on www.elecsuper.com or provided in conjunction with such ElecSuper products. ElecSuper's provision of these resources does not expand or otherwise alter ElecSuper's applicable warranties or warranty disclaimers for ElecSuper products.